

PTVSHC3N7VU

Uni-directional 7V High Capacitance TVS

Description

The PTVSHC3N7VU Transient Voltage Suppressor is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebook computers, and PDA's. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, lower operating voltage, lower clamping voltage and no device degradation when compared to MLVs. The PTVSHC3N7VU protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events. The PTVSHC3N7VU is available in a DFN2×2-3L package with working voltages of 7 volt.

Feature

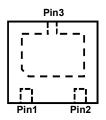
- 4300W Peak pulse power per line (t_P = 8/20µs)
- DFN2×2-3L package
- Response time is typically < 1 ns</p>
- Protect one I/O or power line
- Low clamping Voltage
- RoHS compliant
- Transient protection for data lines to IEC 61000-4-2(ESD)
 ±30KV(air), ±30KV(contact); IEC 61000-4-4 (EFT) 80A (5/50ns)
 IEC 61000-4-5 (Lightning) 260A (8/20us)

Applications

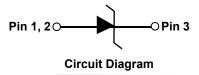
- Cell phone handsets and accessories
- Personal digital assistants (PDA's)
- Notebooks, desktops, and servers
- Portable instrumentation
- Cordless phones
- Digital cameras
- Peripherals
- MP3 players

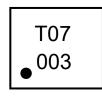
Mechanical Characteristics

- Lead finish:100% matte Sn(Tin)
- Mounting position: Any
- Qualified max reflow temperature:260°C
- Pure tin plating: 7 ~ 17 um
- ➢ Pin flatness∶≤3mil



Pin configuration



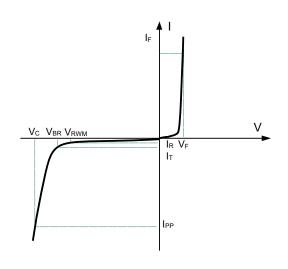


Marking (Top View)

PTVSHC3N7VU

Electronics Parameter

Symbol	Parameter	
VRWM	Peak Reverse Working Voltage	
I _R	Reverse Leakage Current @ V _{RWM}	
V _{BR}	Breakdown Voltage @ I⊤	
Ιτ	Test Current	
I _{PP}	Maximum Reverse Peak Pulse Current	
Vc	Clamping Voltage @ IPP	
P _{PP}	Peak Pulse Power	
CJ	Junction Capacitance	
lF	Forward Current	
VF	Forward Voltage @ I _F	



Electrical characteristics per line@25°C(unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	V _{RWM}				7	V
Breakdown Voltage	V _{BR}	I _t =1mA	8	9	10	V
Reverse Leakage Current	I _R	V _{RWM} =7V			1	μA
Maximum Reverse Peak Pulse Current	Ірр			260		А
Clamping Voltage	Vc	I _{PP} =20A t _P = 8/20µs		9.5	11	V
Clamping Voltage	Vc	I _{PP} =80A t _P = 8/20µs		11	13	V
Clamping Voltage	Vc	I _{PP} =200A t _P = 8/20μs		15	19	V
Junction Capacitance	Cj	V _R =0V f = 1MHz		1700	1900	pF

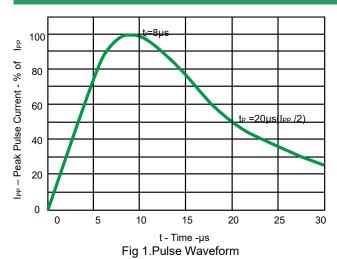
Notes : Measured from pin 3 to pin 1 and pin 2.

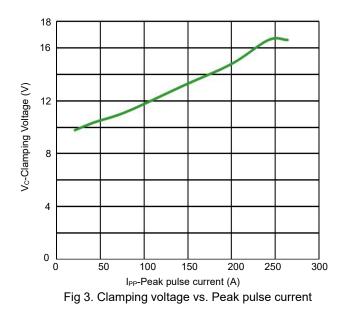
Absolute maximum rating@25℃

Rating	Symbol	Value	Units
Peak Pulse Power ($t_P = 8/20\mu S$)	P _{pp}	4300	w
Lead Soldering Temperature	ΤL	260 (10 sec)	°C
Operating Temperature	TJ	-55 to 150	°C
Storage Temperature	Тѕтс	-55 to 150	°C

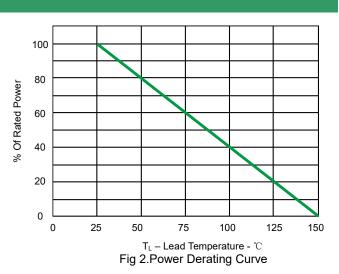
PTVSHC3N7VU

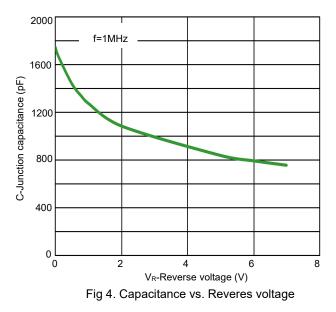
Typical Characteristics





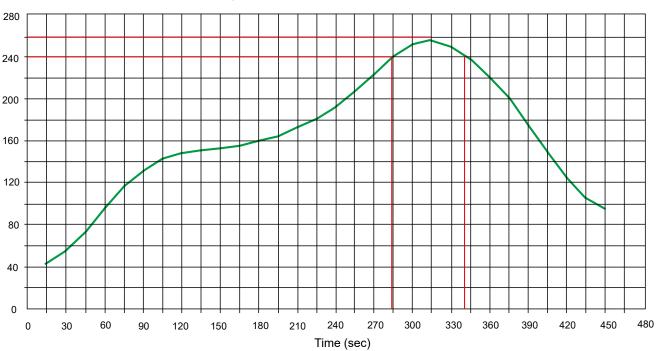
10000 Peak Pulse Power (W) 1000 100 10 100 1000 1 10 Fig 5. Non Repetitive Peak Pulse Power vs. Pulse time





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Solder Reflow Recommendation



Peak Temp=257°C, Ramp Rate=0.802deg. °C/sec

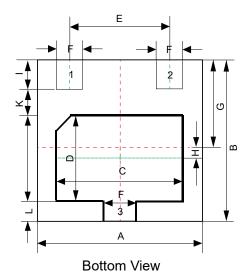
PCB Design

For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

- > Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- Do not make false economies and save copper for the ground connection.
- > Place via holes to ground as close as possible to the anode of the TVS diode.
- > Use as many via holes as possible for the ground connection.
- > Keep the length of via holes in mind! The longer the more inductance they will have.

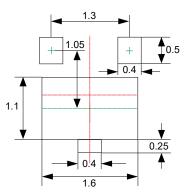
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Product dimension (DFN2×2-3L)





Dim	Millimeters		
	MIN	МАХ	
A	1.90	2.10	
В	1.90	2.10	
С	1.40	1.60	
D	0.90	1.15	
E	1.30BSC		
F	0.25	0.40	
G	0.90	1.10	
н	0.20	0.30	
I	0.32	0.48	
J	0.50	0.65	
К	0.20	0.45	
L	0.15	0.30	



Unit:mm

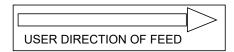
Recommended Soldering Pad

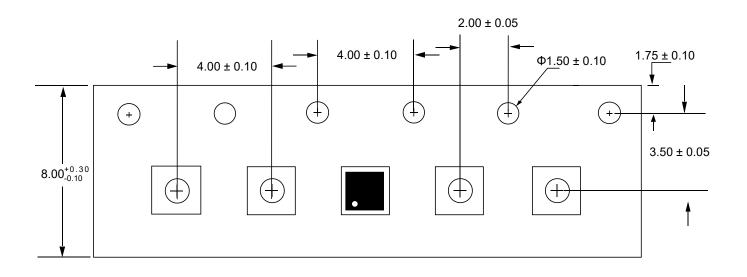
Ordering information

Device	Package	Reel	Shipping
PTVSHC3N7VU	DFN2×2-3L (Pb-Free)	7"	3000 / Tape & Reel

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Load with information





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